

Professional high-speed optical transceiver

OPN-S8G153-3D27SC / OPN-S8G153T-3D27SC
OPN-S8G153-3D27SC-EMG / OPN-S8G153T-3D27SC-EMG
OPN-S8G153-3D27ST / OPN-S8G153T-3D27ST
OPN-S8G153-3D27FC / OPN-S8G153T-3D27FC

CWDM 3.3V / 1.25 Gbps RoHS Compliant Optical Single-Mode Transceiver

PRODUCT FEATURES

- Duplex SC SM Transceiver: OPN-S8G153-3D27SC
- Duplex ST SM Transceiver: OPN-S8G153-3D27ST
- Duplex FC SM Transceiver: OPN-S8G153-3D27FC
 - Compliant with IEEE 802.3z Gigabit Ethernet
- 18-Wavelength CWDM DFB LD Transmitter from 1270 nm to 1610 nm, with step 20 nm
 - 27 dB Link Budget at Least
 - Industry Standard 1 x 9 Footprint
 - Single +3.3 V Power Supply
 - RoHS Compliant
- LVPECL Signal Detect Output: OPN-S8G153-3D27SC
- LVTTTL Signal Detect Output: OPN-S8G153T-3D27SC
 - Wave Solderable
- Class 1 Laser International Safety Standard IEC 60825 Compliant

APPLICATIONS

- Gigabit Ethernet Links
- SONET / SDH Equipment Interconnect
 - Fibre Channel Links
 - CWDM

PRODUCT DESCRIPTION

The OPN-S8G153-3D27SC series single mode transceiver is a low power, high performance CWDM module for bi-directional serial optical data communications such as Gigabit Ethernet and Fibre Channel. There are eighteen center wavelengths available from 1270 nm to 1610 nm, each step 20 nm. A guaranteed minimum optical link budget of 27 dB is offered. The transmitter section uses a multiple quantum well DFB laser and is a class 1 laser compliant according to International Safety Standard IEC 60825. The receiver section uses an integrated InGaAs detector preamplifier (IDP) mounted in an optical header and a limiting post-amplifier IC. A PECL logic interface simplifies interface to external circuitry.

ORDER INFORMATION

P/No.	Bit Rate (Mb/s)	1000 BASE	Power Budget (dB)	Wavelength (nm)	Voltage (V)	Package	Temp. (°C)	TX Power (dBm)	RX Sens. (dBm)	RoHS Compliant
OPN-S8G153-3D27SC	1250	ZX	> 27	CWDM*	3.3	1X9 SC/ST/FC	0 to 70	5 to 0	-27	Y

CWDM Wavelength (0 to 70°C)

Central Wavelength	Min. (nm)	Typ. (nm)	Max. (nm)	Central Wavelength	Min. (nm)	Typ. (nm)	Max. (nm)
127	1264.5	1270	1277.5	145	1444.5	1450	1457.5
129	1284.5	1290	1297.5	147	1464.5	1470	1477.5
131	1304.5	1310	1317.5	149	1484.5	1490	1497.5

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133	1324.5	1330	1337.5	151	1504.5	1510	1517.5
135	1344.5	1350	1357.5	153	1524.5	1530	1537.5
137	1364.5	1370	1377.5	155	1544.5	1550	1557.5
139	1384.5	1390	1397.5	157	1564.5	1570	1577.5
141	1404.5	1410	1417.5	159	1584.5	1590	1597.5
143	1424.5	1430	1437.5	161	1604.5	1610	1617.5

CWDM*: 18 Wavelengths from 1270 nm to 1610 nm, each step 20 nm.

Absolute Maximum Ratings					
Parameter	Symbol	Min	Max	Units	Notes
Storage Temperature	Tstg	-50	85	°C	
Operating Temperature	Topr	0	70	°C	With air flow 1m/sec
Soldering Temperature	---		260	°C	10 seconds on leads only
Power Supply Voltage	Vcc	0	3.6	V	
Input Voltage	---	GND	Vcc	V	
Output Current	Iout	0	30	mA	

Recommended Operating Conditions					
Parameter	Symbol	Min	Typ	Max	Units
Power Supply Voltage	Vcc	3.1	3.3	3.5	V
Operating Temperature	Topr	0		70	°C / air flow 1m/sec
Data Rate			1250	1300	Mb/s
Power Supply Current	Icc		200	280	mA

Transmitter Specifications (0°C < Topr < 70°C, 3.1V < Vcc < 3.5V)						
Parameter	Symbol	Min	Typ	Max	Units	Notes
Optical						
Optical Transmit Power	Po	0	---	5	dBm	1
Output Center Wavelength	λ	$\lambda-5.5$	λ	$\lambda+7.5$	nm	2
Output Spectrum Width	$\Delta\lambda$	---	---	1	nm	-20 dB Width
Side Mode Suppression Ratio	SMSR	30			dB	
Extinction Ratio	ER	9	---	---	dB	
Output Eye	Compliant with Bellcore TR-NWT-000253 and ITU recommendation G.957					
Optical Rise Time	tr			0.26	ns	20% to 80% Values
Optical Fall Time	tf			0.26	ns	20% to 80% Values
Relative Intensity Noise	RIN			-120	dB/Hz	
Total Jitter	TJ			0.227	ns	3
Electrical						
Data Input Current – Low	IL	-350			μA	
Data Input Current – High	I _H			350	μA	
Differential Input Voltage	V _{IH} - V _{IL}	300			mV	
Data Input Voltage – Low	V _{IL} - V _{CC}	-2.0		-1.58	V	4
Data Input Voltage -- High	V _{IH} - V _{CC}	-1.1		-0.74	V	4

Notes: 1. Output power is power coupled into a 9/125 μm single mode fiber.

2. ITU-T G.694.2 CWDM wavelength from 1270 nm to 1610 nm, each step 20 nm.

3. Measured with a 2⁻¹ PRBS.

4. These inputs are compatible with 10K, 10KH and 100K ECL and LVPECL inputs.

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Receiver Specifications (0°C < Topr < 70°C, 3.1V < Vcc < 3.5V)						
Parameter	Symbol	Min	Typ	Max	Units	Notes
Optical						
Sensitivity	---	---	---	-27	dBm	1
Maximum Input Power	Pin	-3		---	dBm	
Signal Detect – Asserted	Pa	---	---	-27	dBm	Transition: low to high
Signal Detect – Deasserted	Pd	-36	---	---	dBm	Transition: high to low
Signal detect -- Hysteresis		1.0	---		dB	
Wavelength of Operation		1100	---	1620	nm	
Electrical						
Data Output Voltage – Low	V _{OL} - V _{CC}	-2.0		-1.58	V	2
Data Output Voltage – High	V _{OH} - V _{CC}	-1.1		-0.74	V	2
Signal Detect Output Voltage -- Low	V _{OL} - V _{CC}	-2.0		-1.58	V	OPN-S8G153-3D27SC
Signal Detect Output Voltage -- High	V _{OH} - V _{CC}	-1.1		-0.74	V	
Signal Detect Output Voltage -- Low	V _{SDL}			0.5	V	OPN-S8G153T-3D27SC
Signal Detect Output Voltage -- High	V _{SDH}	2.0			V	

Notes: 1. Minimum sensitivity and saturation levels at BER=1E-12 for a 2⁷-1 PRBS at ER=9 dB.

2. These outputs are compatible with 10K, 10KH and 100K ECL and PECL outputs.

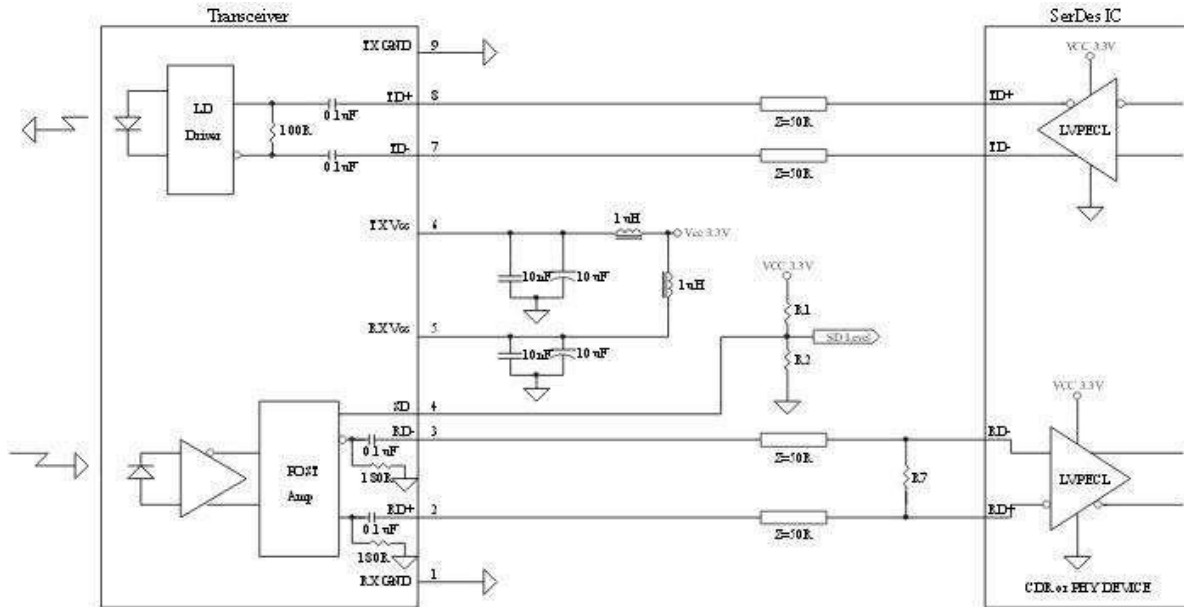
CONNECTION DIAGRAM

Receiver Signal Ground	1 (Rx GND)	○
Receiver Data Out	2 (RD+)	N/C
Receiver Data Out Bar	3 (RD-)	
Signal Detect	4 (SD)	
Receiver Power Supply	5 (Rx Vcc)	TOP VIEW
Transmitter Power Supply	6 (Tx Vcc)	
Transmitter Data In Bar	7 (TD-)	
Transmitter Data In	8 (TD+)	N/C
Transmitter Signal Ground	9 (Tx GND)	○

PIN	Symbol	Notes
1	Rx GND	Directly connect this pin to the receiver ground plane
2	RD+	See recommended circuit schematic
3	RD-	See recommended circuit schematic
4	SD	Active high on this indicates a received optical signal
5	Rx Vcc	+3.3V dc power for the receiver section
6	Tx Vcc	+3.3V dc power for the transmitter section
7	TD-	See recommended circuit schematic
8	TD+	See recommended circuit schematic
9	Tx GND	Directly connect this pin to the transmitter ground plane

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RECOMMENDED CIRCUIT SCHEMATIC



For TTL SD Level, $R1=R2=N.C.$, $R7=100\text{ ohm}$

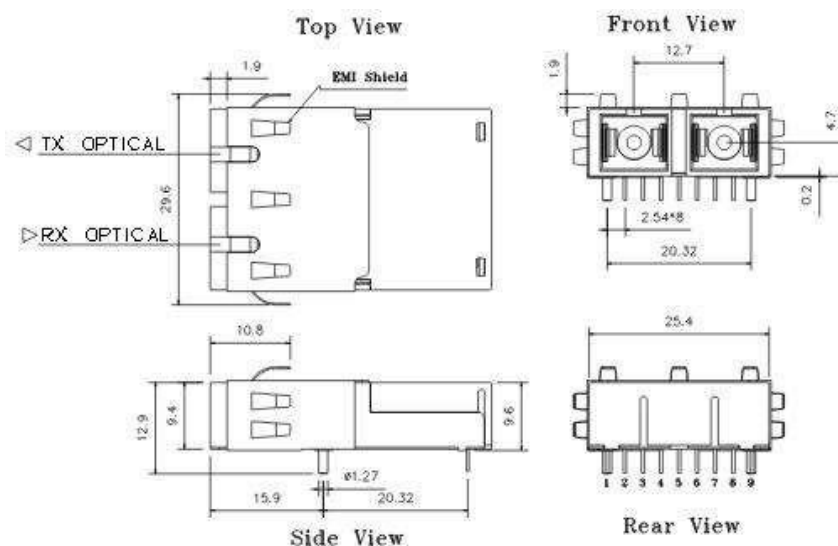
For PECL SD Level, $R1=130\text{ ohm}$, $R2=82\text{ ohm}$, $R7=100\text{ ohm}$

The split-load terminations for ECL signals need to be located at the input of devices receiving those ECL signals. The power supply filtering is required for good EMI performance. Use short tracks from the inductor L1/L2 to the module Rx Vcc and Tx Vcc. A GND plane under the module is required for good EMI and sensitivity performance.

PACKAGE DIAGRAM

Units in mm

1) SC Type With Extended Shielding



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